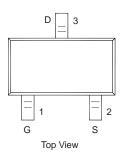


N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A) ^a	Q _g (Typ.)			
30	0.021 at V _{GS} = 10 V	6	2.1 nC			
	0.022 at V _{GS} = 4.5 V	4.8	2.1110			





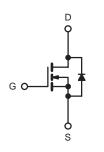
FEATURES

- DT-Trench Power MOSFET
- 100 % Rg Tested
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

DC/DC Converter





N-Channel MOSFET

Parameter	Symbol	Limit	Unit		
Drain-Source Voltage		V _{DS}	30	V	
Gate-Source Voltage		V _{GS}	± 20	V	
	T _C = 25 °C		6.0 ^a		
Continuous Drain Current ($T_1 = 150 \ ^{\circ}C$)	T _C = 70 °C	l _D	4.5		
	T _A = 25 °C	טי	6.0		
	T _A = 70 °C		4.3	A	
Pulsed Drain Current		I _{DM}	20		
Continuous Courses Drain Diada Current	T _C = 25 °C		5.4		
Continuous Source-Drain Diode Current	T _A = 25 °C	۱ _s	1.2 ^{b, c}		
	T _C = 25 °C		1.7		
Maximum Power Dissipation	T _C = 70 °C	P _D	1.1	W	
	T _A = 25 °C	'U	1.1 ^{b, c}	••	
	T _A = 70 °C	1	0.7 ^{b, c}		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	℃	
Soldering Recommendations (Peak Temperations)		260			

THERMAL RESISTANCE RATINGS							
Parameter		Symbol	Typical	Maximum	Unit		
Maximum Junction-to-Ambient ^{b, d}	t ≤ 5 s	R _{thJA}	90	115	°C/W		
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	60	75	0/00		

Notes:

a. Package limited

b. Surface Mounted on 1" x 1" FR4 board.

c. t = 5 s.

d. Maximum under steady state conditions is 130 $^{\circ}\text{C/W}.$

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static					•	
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0 V, I _D = 250 μA	30			V
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	L 250 ··· A		31		mV/°C
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	I _D = 250 μA		- 5		
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	0.6		1.6	V
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA
	I _{DSS}	$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1	μA
Zero Gate Voltage Drain Current		$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 55 ^{\circ}\text{C}$			10	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$	10			Α
		V _{GS} = 10 V, I _D = 3.2 A		0.021	0.024	Ω
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 2.8 A		0.022	0.033	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 4.8 A		11		S
Dynamic ^b					I	1
Input Capacitance	C _{iss}			235		
Output Capacitance	C _{oss}	V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz		45		pF
Reverse Transfer Capacitance	C _{rss}			17		
Total Gate Charge	Q _g	$V_{DS} = 15 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 3.4 \text{ A}$		4.5	6.7	nC
				2.1	3.2	
Gate-Source Charge	Q _{gs}	V_{DS} = 15 V, V_{GS} = 4.5 V, I_{D} = 3.4 A		0.85		
Gate-Drain Charge	Q _{gd}			0.65		
Gate Resistance	Rg	f = 1 MHz	0.8	4.4	8.8	Ω
Turn-On Delay Time	t _{d(on)}			12	20	- ns
Rise Time	t _r	V_{DD} = 15 V, R_{L} = 5.6 Ω		50	75	
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 2.7 \text{ A}, V_{GEN} = 4.5 \text{ V}, R_g = 1 \Omega$		12	20	
Fall Time	t _f			22	35	
Turn-On Delay Time	t _{d(on)}			5	10	
Rise Time	t _r	V_{DD} = 15 V, R _L = 5.6 Ω		12	20	
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 2.7 \text{ A}, V_{GEN} = 10 \text{ V}, \text{ R}_g = 1 \Omega$		10	15	
Fall Time	t _f			5	10	
Drain-Source Body Diode Characteristic	cs				•	1
Continuous Source-Drain Diode Current	ا _S	T _C = 25 °C			5.4	^
Pulse Diode Forward Current	I _{SM}			1	18	A
Body Diode Voltage	V _{SD}	$I_{S} = 2.7 \text{ A}, V_{GS} = 0 \text{ V}$		0.8	1.2	V
Body Diode Reverse Recovery Time	t _{rr}			10	20	ns
Body Diode Reverse Recovery Charge	Q _{rr}			5	10	nC
Reverse Recovery Fall Time	t _a	$I_F = 2.7 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, \text{ T}_J = 25 ^\circ\text{C}$		6		1
Reverse Recovery Rise Time	t _b			4	1	ns

Notes:

a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

5 V_{GS} = 10 V thru 4 V 4 ID - Drain Current (A) I_D - Drain Current (A) 3 2 $V_{GS} = 3 V$ 1 $V_{GS} = 1 V$ 0 2.5 3.0 0.0 0.5 1.0 1.5 2.0 V_{DS} - Drain-to-Source Voltage (V) **Output Characteristics** 0.05 0.04 $R_{DS(on)}$ - On-Resistance (Ω) C - Capacitance (pF) 0.03 V_{GS} = 4.5 V 0.02 $V_{GS} = 10 V$ 0.01 0.00 0 1 2 3 4 5 I_D - Drain Current (A) **On-Resistance vs. Drain Current and Gate Voltage** 10 $I_{D} = 3.4 \text{ A}$ $V_{DS} = 7.5 V$ V_{GS} - Gate-to-Source Voltage (V) 8 R_{DS(on)} - On-Resistance V_{DS} = 24 V 6 V_{DS} = 15 V 4 2 0

Q_g - Total Gate Charge (nC) Gate Charge

3

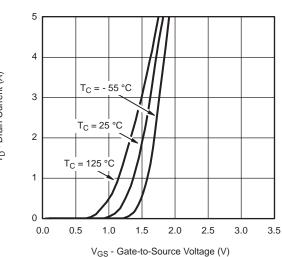
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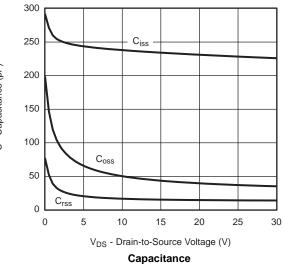
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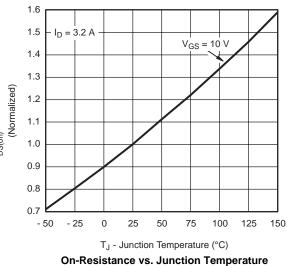
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1



Transfer Characteristics

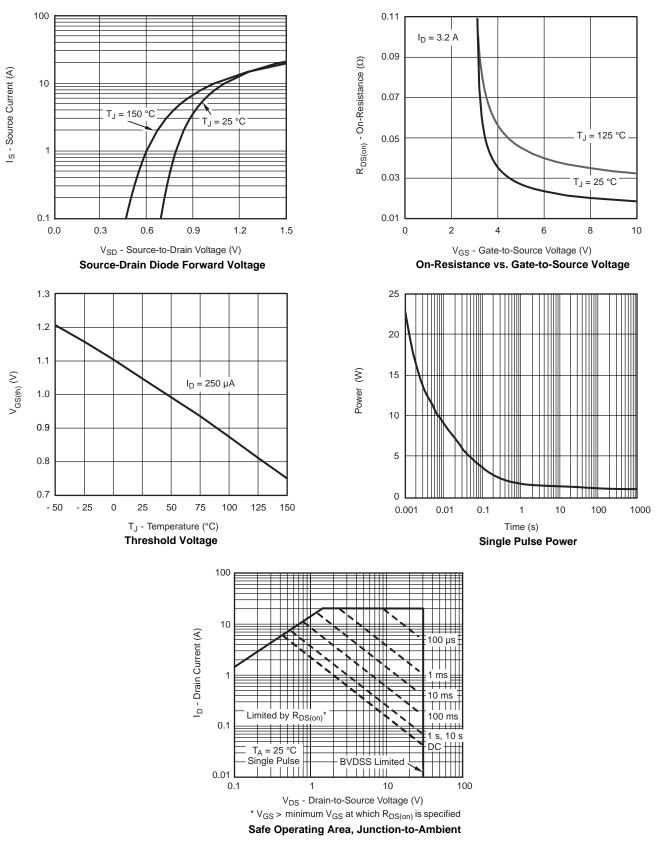




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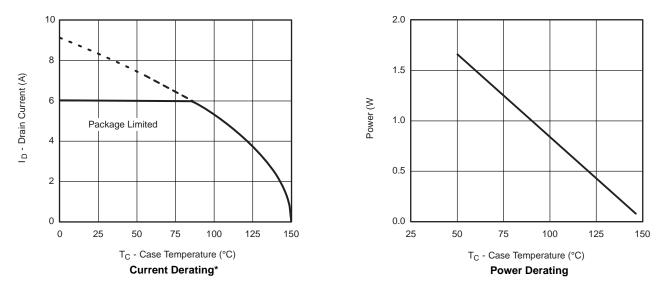
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

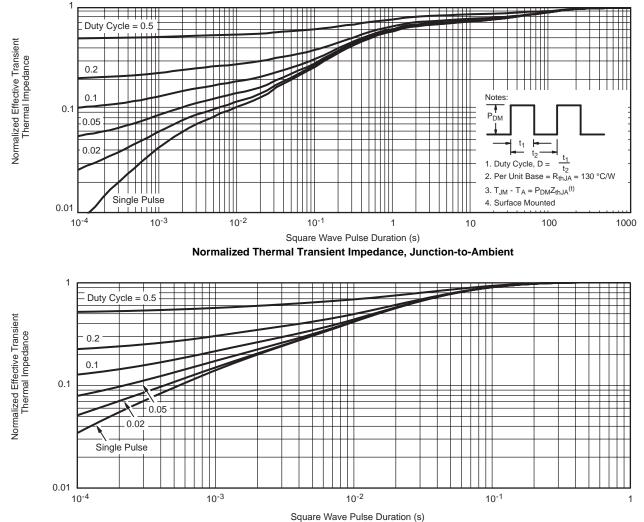


* The power dissipation P_D is based on $T_{J(max)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

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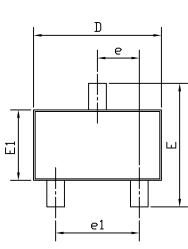


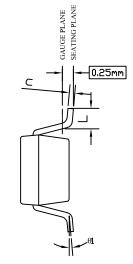


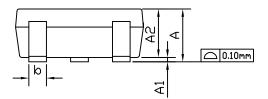
Normalized Thermal Transient Impedance, Junction-to-Foot



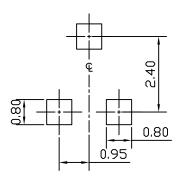








RECOMMENDED LAND PATTERN



SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES		
SIMBOLS	MIN	NOM	MAX	MIN	NOM	MAX
A	0.85		1.25	0.033		0.049
A1	0.00		0.13	0.000		0.005
A2	0.70	1.00	1.15	0.028	0.039	0.045
b	0.30	0.40	0.50	0.012	0.016	0.020
с	0.08	0.13	0.20	0.003	0.005	0.008
D	2.80	2.90	3.10	0.110	0.114	0.122
E	2.60	2.80	3.00	0.102	0.110	0.118
E1	1.40	1.60	1.80	0.055	0.063	0.071
e	0.95 BSC			0.037 BSC		
e1	1.90 BSC			0.075 BSC		
L	0.30		0.60	0.012		0.024
θ1	0°	5°	8°	0°	5°	8°

UNIT: mm

NOTE

1. PACKAGE BODY SIZES EXCLUDE MOLD FLASH OR GATE BURRS.

MOLD FLASH AT THE NON-LEAD SIDES SHOULD BE LESS THAN 5 MILS EACH.

2. TOLERANCE ± 0.100 mm (4 mil) UNLESS OTHERWISE SPECIFIED.

3. DIMENSION L IS MEASURED IN GAUGE PLANE.

4. CONTROLLING DIMENSION IS MILLIMETER. CONVERTED INCH DIMENSIONS ARE NOT NECESSARILY EXACT.

5. ALL DIMENSIONS ARE IN MILLIMETERS.



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